

Low voltage fast-switching PNP power transistor

Datasheet - production data

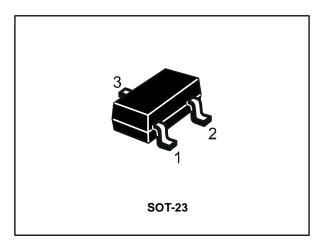
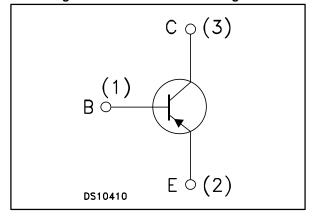


Figure 1: Internal schematic diagram



Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

Applications

- LED
- Battery charger
- Motor and relay driver
- Voltage regulation

Description

The device in a PNP transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

The complementary NPN is the 2STR1160.

Table 1: Device summary

Order code	Marking	Package	Packing
2STR2160	2160	SOT-23	Tape and reel

Contents 2STR2160

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2STR2160 Electrical ratings

1 Electrical ratings

Table 2: Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-60	V
V_{CEO}	Collector-emitter voltage (I _B = 0)	-60	V
V _{EBO}	Emitter-base voltage (Ic = 0)	-5	V
lc	Collector current	-1	Α
I _{CM}	Collector peak current (t _P < 5ms)	-2	Α
Ptot	Total dissipation at T _{amb} = 25°C	0.5	W
Tstg	Storage temperature -65 t		°C
TJ	Max. operating junction temperature	150	°C

Table 3: Thermal data

Symbol	Parameter	Value	Unit
R _{thj-amb} ⁽¹⁾	Thermal resistance junction-amb max	250	°C/W

Notes:

⁽¹⁾Device mounted on PCB area of 1 cm²

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 4: Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
Ісво	Collector cut-off current (I _E =0)	V _{CB} = -60 V			-0.1	μΑ
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5 V			-0.1	μΑ
V _(BR) CBO	Collector-base breakdown voltage (I _E = 0)	Ic = -100 μA	-60			٧
V _(BR) CEO ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = -10 mA	-60			V
V _{(BR)EBO}	Emitter-base breakdown voltage (Ic = 0)	Ιε = -100 μΑ	-5			V
	Collector-emitter saturation voltage	$I_C = -0.5 \text{ A } I_B = -50 \text{ mA}$			260	mV
V _{CE(sat)}		$I_C = -1 A I_B = -100 \text{ mA}$			480	mV
V _{BE} (sat)	Base-emitter saturation voltage	I _C = -1 A I _B = -100 mA			1.3	٧
		Ic = -0.5 A VcE = -2V	180		560	
h _{FE}	DC current gain	$I_C = -1 \text{ A V}_{CE} = -2 \text{ V}$	45			
		Ic = -2 A VcE = -2 V		30		
	Resistive load					
t _{on}	Turn-on time	$I_C = -1.5 \text{ A V}_{CC} = -10 \text{ V}$		220		ns
t off	Turn-off time	$I_{B1} = -I_{B2} = -150 \text{ mA}$ $V_{BB(off)} = 5 \text{ V}$		500		ns

Notes:

 $^{^{(1)}\}text{Pulse}$ test: pulse duration = 300 µs, duty cycle \leq 1.5 %

3 Package mechanical data

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3.1 SOT-23 mechanical data

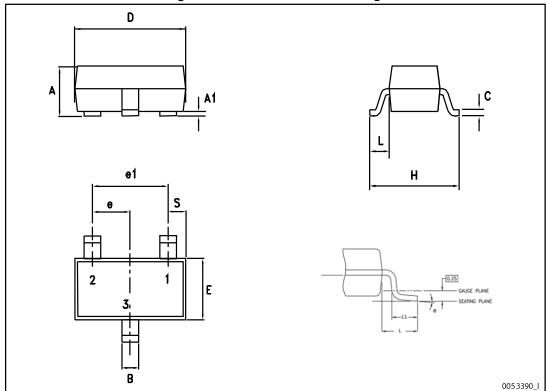
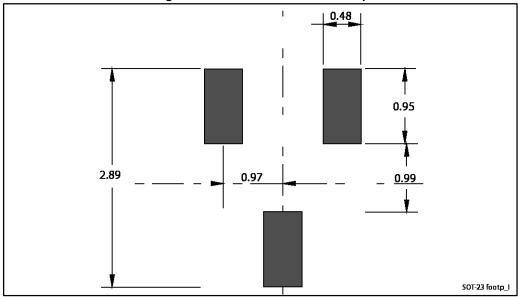


Figure 2: SOT-23 mechanical drawing

Table 5: SOT-23 mechanical data

Dim.	mm			
Dilli.	Min.	Тур.	Max.	
А	0.89		1.40	
A1	0		0.10	
В	0.30		0.51	
С	0.085		0.18	
D	2.75		3.04	
е	0.85		1.05	
e1	1.70		2.10	
Е	1.20		1.75	
Н	2.10		3.00	
L		0.60		
S	0.35		0.65	
L1	0.25		0.55	
а	0°		8°	

Figure 3: SOT-23 recommended footprint





Dimensions are in mm.

2STR2160 Revision history

4 Revision history

Table 6: Document revision history

Date	Revision	Changes
18-Jun-2008	1	Initial release
08-May-2014	2	Updated Section 3: "Package mechanical data".
13-Mar-2015	3	Updated marking in Table 1: "Device summary"

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